

Filed Electronically

PATENT APPLICATION
Docket No. 14321.63

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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|--------------------------|----------------------------------|------------|
| In re application of |) | |
| |) | |
| Toshiki Makimoto, et al. |) | |
| |) | |
| Serial No.: | 10/516,380 |) Art Unit |
| | |) 2818 |
| Filing Date: | November 30, 2004 |) |
| | |) |
| Confirmation No.: | 2860 |) |
| | |) |
| For: | P-TYPE NITRIDE SEMICONDUCTOR |) |
| | STRUCTURE AND BIPOLAR TRANSISTOR |) |
| | |) |
| Examiner: | Tram Hoang Nguyen |) |

AMENDMENT "D" AND RESPONSE TO FINAL OFFICE ACTION

Commissioner for Patents
PO Box 1450
Alexandria, Virginia 22313-1450

Examiner:

Applicant submits this paper in response to the Final Office Action mailed June 11, 2008 and in conjunction with a Request for Continued Examination (RCE). Reconsideration is respectfully requested in view of the following remarks:

Amendments to the Claims begin on page 2 of this paper.

Remarks begin on page 7 of this paper.